NSN 5961-01-497-5803

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-497-5803 **Inclosure Material:** Ceramic **Overall Length:** Between 0.895 inches and 0.925 inches **Terminal Length:** 0.165 inches **Overall Height:** 0.192 inches **Overall Width:** Between 0.450 inches and 0.480 inches **Function For Which Designed:** Transient suppressor **End Application:** 2350-01-455-3174 **Component Name And Quantity:** 15 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 12.0 reverse supression voltage all semiconductor and 13.3 breakdown voltage, dc all semiconductor **Current Rating Per Characteristic:** 10.00 amperes forward current, average preset all semiconductor device diode and 2.00 microamperes source cutoff current of standard range all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius ambient air and 150.0 degrees celsius ambient air **Special Features:** The h1 in the p/n represents 100% jantx level screening **Terminal Type And Quantity:** 16 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No